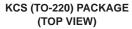
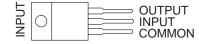
- 3-Terminal Regulators
- **Output Current Up To 1.5 A**
- **No External Components**
- **Internal Thermal Overload Protection**
- **High-Power Dissipation Capability**
- **Internal Short-Circuit Current Limiting**
- **Output Transistor Safe-Area Compensation**

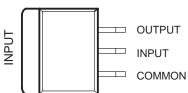
description/ordering information

This fixed-negative-voltage series integrated-circuit voltage regulators is designed to complement Series µA7800 in a wide range of applications. These applications include on-card regulation for elimination of noise and distribution









problems associated with single-point regulation. Each of these regulators can deliver up to 1.5 A of output current. The internal current limiting and thermal shutdown features of these regulators essentially make them immune to overload. In addition to use as fixed-voltage regulators, these devices can be used with external components to obtain adjustable output voltages and currents and also as the power-pass element in precision regulators.

ORDERING INFORMATION

TJ	V _{O(NOM)} (V)	PACKAGET		ORDERABLE PART NUMBER	TOP-SIDE MARKING
	-15	PowerFLEX™ (KTE)	Reel of 2000	μΑ7915CKTER	μA7915C
	-13	TO-220, short shoulder (KCS)	Tube of 50	μΑ7915CKCS	μA7915C
	40	PowerFLEX (KTE)	Reel of 2000	μΑ7912CKTER	μA7912C
0°C to 125°C	–12	TO-220, short shoulder (KCS)	Tube of 50	μΑ7912CKCS	μA7912C
0 0 10 125 0		PowerFLEX (KTE)	Reel of 2000	μΑ7908CKTER	μA7908C
	-8	TO-220, short shoulder (KCS)	Tube of 50	μA7908CKCS	μA7908C
	_	PowerFLEX (KTE)	Reel of 2000	μΑ7905CKTER	μA7905C
	-5	TO-220, short shoulder (KCS)	Tube of 50	μA7905CKCS	μA7905C

[†]Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

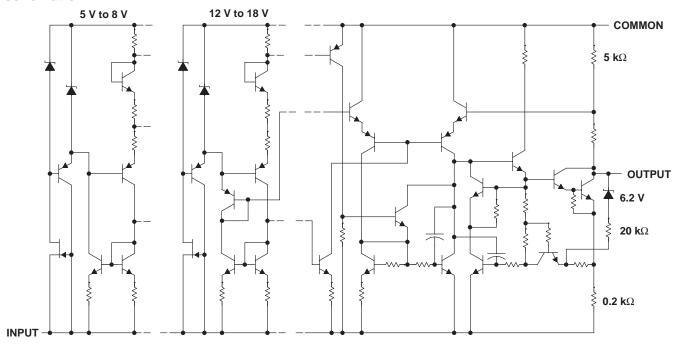


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PowerFLEX is a trademark of Texas Instruments.



schematic



All component values are nominal.

absolute maximum ratings over virtual junction temperature range (unless otherwise noted)†

Input voltage, V _I –	·35 V
Operating virtual junction temperature, T _J	50°C
Storage temperature range, T _{stg} –65 to 15	50°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

package thermal data (see Note 1)

PACKAGE	BOARD	θЈС	$^{ heta}$ JA
PowerFLEX (KTE)	High K, JESD 51-5	3°C/W	23°C/W
TO-220 (KCS)	High K, JESD 51-5	3°C/W	19°C/W

NOTE 1: Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.

recommended operating conditions

			MIN	MAX	UNIT
		μΑ7905C	-7	-25	
V.	V _I Input voltage	μΑ7908C	-10.5	-25	V
V		μA7912C	-14.5	-25	V
		μΑ7915C	-17.5	-25	
lO	Output current	·		1.5	Α
TJ	Operating virtual junction temperature		0	125	°C



electrical characteristics at specified virtual junction temperature, $V_I = -10 \text{ V}$, $I_O = 500 \text{ mA}$ (unless otherwise noted)

DADAMETED	TEST CONDITIONS	T	μ Α7905C			UNITS
PARAMETER	TEST CONDITIONS	TJ [†]	MIN	TYP	MAX	UNIIS
		25°C	-4.8	-5	-5.2	
Output voltage‡	I_{O} = 5 mA to 1 A, P \leq 15 W V_{I} = -7 V to -20 V,	0°C to 125°C	-4.75		-5.25	V
Input regulation	$V_I = -7 \text{ V to } -25 \text{ V}$			12.5	50	mV
Input regulation	V _I = -8 V to -12 V			4	15	IIIV
Ripple rejection	$V_{\parallel} = -8 \text{ V to } -18 \text{ V}, \qquad f = 120 \text{ Hz}$	0°C to 125°C	54	60		dB
Outrot as mulation	I _O = 5 mA to 1.5 A			15	100	\/
Output regulation	I _O = 250 mA to 750 mA			5	50	mV
Temperature coefficient of output voltage	I _O = 5 mA	0°C to 125°C		-0.4		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz	25°C		125		μV
Dropout voltage	I _O = 1 A	25°C		1.1		V
Bias current		25°C		1.5	2	mA
Diag surrent shares	$V_{ } = -7 \text{ V to } -25 \text{ V}$			0.15	0.5	A
Bias current change	I _O = 5 mA to 1 A			0.08	0.5	mA
Peak output current		25°C		2.1		Α

Thuse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output. This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, $V_I = -11 \text{ V}$, $I_O = 500 \text{ mA}$ (unless otherwise noted)

DADAMETED	TEST CONDITIONS	t	μ	UNITS		
PARAMETER	TEST CONDITIONS	TJ [†]	MIN	TYP	MAX	UNITS
		25°C	-5.75	-6	-6.25	
Output voltage‡	$I_O = 5$ mA to 1 A, $V_I = -8$ V to -21 V, $P \le 15$ W	0°C to 125°C	-5.7		-6.3	V
long translation	$V_{I} = -8 \text{ V to } -25 \text{ V}$			12.5	120	mV
Input regulation	V _I = -9 V to -13 V			4	60	IIIV
Ripple rejection	$V_I = -9 \text{ V to } -19 \text{ V}, \qquad f = 120 \text{ Hz}$	0°C to 125°C	54	60		dB
Outrout regulation	I _O = 5 mA to 1.5 A			15	120	mV
Output regulation	I _O = 250 mA to 750 mA]		5	60	IIIV
Temperature coefficient of output voltage	$I_O = 5 \text{ mA}$	0°C to 125°C		-0.4		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz	25°C		150		μV
Dropout voltage	I _O = 1 A	25°C		1.1		V
Bias current		25°C		1.5	2	mA
Dies surrent shares	V _I = −8 V to −25 V			0.15	1.3	A
Bias current change	I _O = 5 mA to 1 A]		0.08	0.5	mA
Peak output current		25°C		2.1		Α

[†] Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output. ‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.



electrical characteristics at specified virtual junction temperature, $V_I = -14 \text{ V}$, $I_O = 500 \text{ mA}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T.:t	μ		UNITS	
PARAMETER	TEST CONDITIONS	T _J †	MIN	TYP	MAX	UNITS
		25°C	-7.7	-8	-8.3	
Output voltage‡	I_O = 5 mA to 1 A, V_I = -10.5 V to -23 V, $P \le 15$ W	0°C to 125°C	-7.6		-8.4	V
lanut regulation	$V_{I} = -10.5 \text{ V to } -25 \text{ V}$			12.5	160	m)/
Input regulation	V _I = -11 V to -17 V	1		4	80	mV
Ripple rejection	$V_I = -11.5 \text{ V to } -21.5 \text{ V}, \text{ f} = 120 \text{ Hz}$	0°C to 125°C	54	60		dB
Output no mulation	I _O = 5 mA to 1.5 A			15	160	\/
Output regulation	I _O = 250 mA to 750 mA	1		5	80	mV
Temperature coefficient of output voltage	$I_O = 5 \text{ mA}$	0°C to 125°C		-0.6		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz	25°C		200		μV
Dropout voltage	I _O = 1 A	25°C		1.1		V
Bias current		25°C		1.5	2	mA
Dies surrent change	$V_{I} = -10.5 \text{ V to } -25 \text{ V}$			0.15	1	A
Bias current change	I _O = 5 mA to 1 A]		0.08	0.5	mA
Peak output current		25°C		2.1		Α

Thuse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output. This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, $V_I = -19 \text{ V}$, $I_O = 500 \text{ mA}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	t	μ	UNITS		
PARAMETER	TEST CONDITIONS	TJ [†]	MIN	TYP	MAX	UNITS
		25°C	-11.5	-12	-12.5	
Output voltage‡	I_{O} = 5 mA to 1 A, V_{I} = -14.5 V to -27 V, $P \le$ 15 W	0°C to 125°C	-11.4		-12.6	V
lanut regulation	$V_{I} = -14.5 \text{ V to } -25 \text{ V}$			5	80	mV
Input regulation	V _I = -16 V to -22 V	1		3	30	IIIV
Ripple rejection	$V_I = -15 \text{ V to } -25 \text{ V}, f = 120 \text{ Hz}$	0°C to 125°C	54	60		dB
Output regulation	I _O = 5 mA to 1.5 A			15	200	mV
Output regulation	I _O = 250 mA to 750 mA	1		5	75	IIIV
Temperature coefficient of output voltage	I _O = 5 mA	0°C to 125°C		-0.8		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz	25°C		300		μV
Dropout voltage	I _O = 1 A	25°C		1.1		V
Bias current		25°C		2	3	mA
Dies surrent shangs	V _I = -14.5 V to -25 V			0.04	0.5	A
Bias current change	I _O = 5 mA to 1 A]		0.06	0.5	mA
Peak output current		25°C		2.1		Α

[†] Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output. ‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.



electrical characteristics at specified virtual junction temperature, $V_I = -23 \text{ V}$, $I_O = 500 \text{ mA}$ (unless otherwise noted)

DADAMETED	TEST CONDITIONS	- +	μ Α7915C			UNITS
PARAMETER	TEST CONDITIONS	TJ [†]	MIN	TYP	MAX	UNIIS
		25°C	-14.4	-15	-15.6	
Output voltage‡	I_{O} = 5 mA to 1 A, V_{I} = -17.5 V to -25 V, $P \le$ 15 W	0°C to 125°C	-14.25		-15.75	V
Input regulation	V _I = -17.5 V to -25 V			5	100	m)/
Input regulation	V _I = -20 V to -25 V	1		3	50	mV
Ripple rejection	$V_{I} = -18.5 \text{ V to } -25 \text{ V}, f = 120 \text{ Hz}$	0°C to 125°C	54	60		dB
Outrant as an lating	I _O = 5 mA to 1.5 A			20	300	\/
Output regulation	I _O = 250 mA to 750 mA	1		8	150	mV
Temperature coefficient of output voltage	I _O = 5 mA	0°C to 125°C		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz	25°C		375		μV
Dropout voltage	I _O = 1 A	25°C		1.1		V
Bias current		25°C		2	3	mA
Diag surrent shares	V _I = -17.5 V to -25 V			0.04	0.5	A
Bias current change	I _O = 5 mA to 1 A	1		0.06	0.5	mA
Peak output current		25°C		2.1		Α

Thuse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output. This specification applies only for dc power dissipation permitted by absolute maximum ratings.

electrical characteristics at specified virtual junction temperature, $V_I = -27 \text{ V}$, $I_O = 500 \text{ mA}$ (unless otherwise noted)

DADAMETED	TEST CONDITIONS	t	μ	UNITS		
PARAMETER	TEST CONDITIONS	TJ [†]	MIN	TYP	MAX	UNITS
		25°C	-17.3	-18	-18.7	
Output voltage‡	I_{O} = 5 mA to 1 A, V_{I} = -21 V to -33 V, $P \le 15$ W	0°C to 125°C	-17.1		-18.9	V
lanut regulation	V _I = -21 V to -33 V			5	360	mV
Input regulation	V _I = -24 V to -30 V			3	180	IIIV
Ripple rejection	V _I = -22 V to -32 V, f = 120 Hz	0°C to 125°C	54	60		dB
Output regulation	I _O = 5 mA to 1.5 A			30	360	mV
Output regulation	I _O = 250 mA to 750 mA	1		10	180	IIIV
Temperature coefficient of output voltage	I _O = 5 mA	0°C to 125°C		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz	25°C		450		μV
Dropout voltage	I _O = 1 A	25°C		1.1		V
Bias current		25°C		2	3	mA
Dies surrent change	V _I = -21 V to -33 V			0.04	1	A
Bias current change	I _O = 5 mA to 1 A]		0.06	0.5	mA
Peak output current		25°C		2.1		Α

[†] Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output. ‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.



μ**A7900 SERIES NEGATIVE-VOLTAGE REGULATORS**

SLVS058F - JUNE 1976 - REVISED FEBRUARY 2005

electrical characteristics at specified virtual junction temperature, $V_I = -33 \text{ V}$, $I_O = 500 \text{ mA}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T.1	μ		UNITS	
PARAMETER	TEST CONDITIONS	TJ [†]	MIN	TYP	MAX	UNITS
		25°C	-23	-24	-25	
Output voltage‡	$I_O = 5$ mA to 1 A, $V_I = -27$ V to -38 V, $P \le 15$ W	0°C to 125°C	-22.8		-25.2	V
Input regulation	$V_{I} = -27 \text{ V to } -38 \text{ V}$			5	480	mV
Input regulation	$V_{I} = -30 \text{ V to } -36 \text{ V}$			3	240	IIIV
Ripple rejection	$V_I = -28 \text{ V to } -38 \text{ V}, \text{ f} = 120 \text{ Hz}$	0°C to 125°C	54	60		dB
Outrot as relation	I _O = 5 mA to 1.5 A			85	480	\/
Output regulation	I _O = 250 mA to 750 mA			25	240	mV
Temperature coefficient of output voltage	$I_O = 5 \text{ mA}$	0°C to 125°C		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz	25°C		600		μV
Dropout voltage	I _O = 1 A	25°C		1.1		V
Bias current		25°C		2	3	mA
Dies surrent change	$V_{I} = -27 \text{ V to } -38 \text{ V}$			0.04	1	A
Bias current change	I _O = 5 mA to 1 A	7		0.06	0.5	mA
Peak output current		25°C		2.1		Α

[†] Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 2-μF capacitor across the input and a 1-μF capacitor across the output. ‡ This specification applies only for dc power dissipation permitted by absolute maximum ratings.







i.com 8-Mar-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
UA7905CKC	OBSOLETE	TO-220	KC	3		None	Call TI	Call TI
UA7905CKCS	ACTIVE	TO-220	KCS	3	50	None	Call TI	Level-NC-NC-NC
UA7905CKTER	ACTIVE	PFM	KTE	3	2000	None	Call TI	Level-1-220C-UNLIM
UA7908CKC	OBSOLETE	TO-220	KC	3		None	Call TI	Call TI
UA7908CKCS	ACTIVE	TO-220	KCS	3	50	None	Call TI	Level-NC-NC-NC
UA7908CKTER	ACTIVE	PFM	KTE	3	2000	None	Call TI	Level-1-220C-UNLIM
UA7912CKC	OBSOLETE	TO-220	KC	3		None	Call TI	Call TI
UA7912CKCS	ACTIVE	TO-220	KCS	3	50	None	Call TI	Level-NC-NC-NC
UA7912CKTER	ACTIVE	PFM	KTE	3	2000	None	Call TI	Level-1-220C-UNLIM
UA7915CKC	OBSOLETE	TO-220	KC	3		None	Call TI	Call TI
UA7918CKC	OBSOLETE	TO-220	KC	3		None	Call TI	Call TI
UA7924CKC	OBSOLETE	TO-220	KC	3		None	Call TI	Call TI

 $^{(1)}$ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - May not be currently available - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

None: Not yet available Lead (Pb-Free).

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

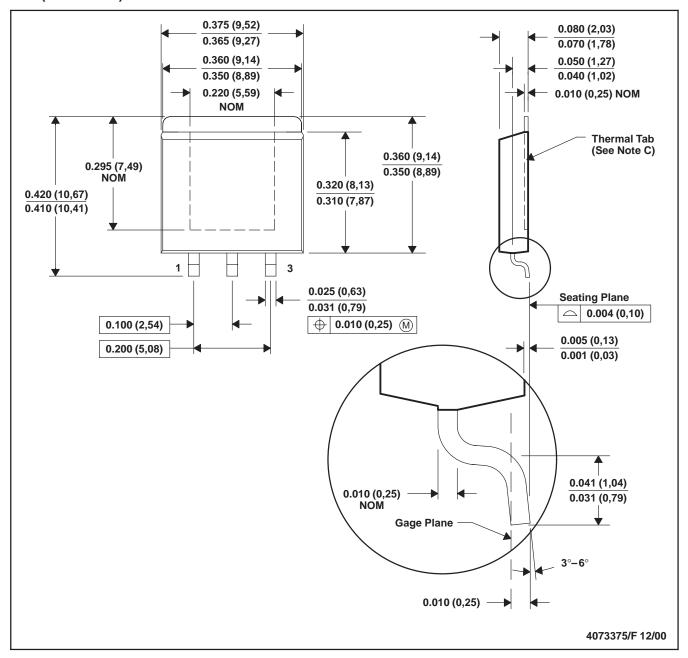
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDECindustry standard classifications, and peak solder temperature.

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KTE (R-PSFM-G3)

PowerFLEX™ PLASTIC FLANGE-MOUNT



NOTES: A. All linear dimensions are in inches (millimeters).

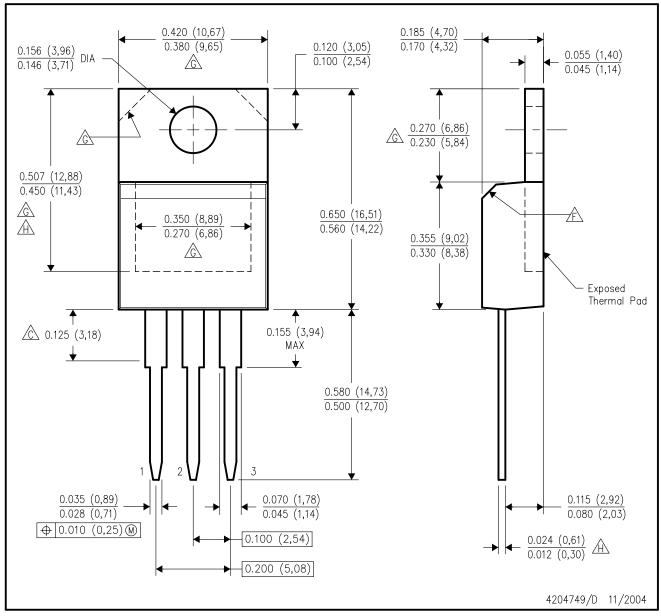
- B. This drawing is subject to change without notice.
- C. The center lead is in electrical contact with the thermal tab.
- D. Dimensions do not include mold protrusions, not to exceed 0.006 (0,15).
- E. Falls within JEDEC MO-169

PowerFLEX is a trademark of Texas Instruments.



KCS (R-PSFM-T3)

PLASTIC FLANGE-MOUNT PACKAGE



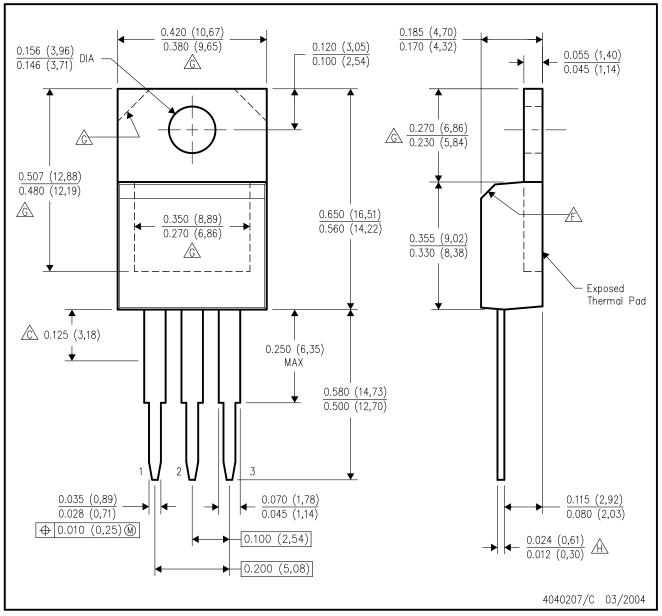
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Lead dimensions are not controlled within this area.
- D. All lead dimensions apply before solder dip.
- E. The center lead is in electrical contact with the mounting tab.
- The chamfer is optional.
- Thermal pad contour optional within these dimensions.
- Falls within JEDEC T0—220 variation AB, except minimum lead thickness and minimum exposed pad length.



KC (R-PSFM-T3)

PLASTIC FLANGE-MOUNT PACKAGE



NOTES: A

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Lead dimensions are not controlled within this area.
- D. All lead dimensions apply before solder dip.
- E. The center lead is in electrical contact with the mounting tab.
- The chamfer is optional.
- Thermal pad contour optional within these dimensions.
- ⚠ Falls within JEDEC T0—220 variation AB, except minimum lead thickness.



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